

TOSHIBA

HN1D01FU

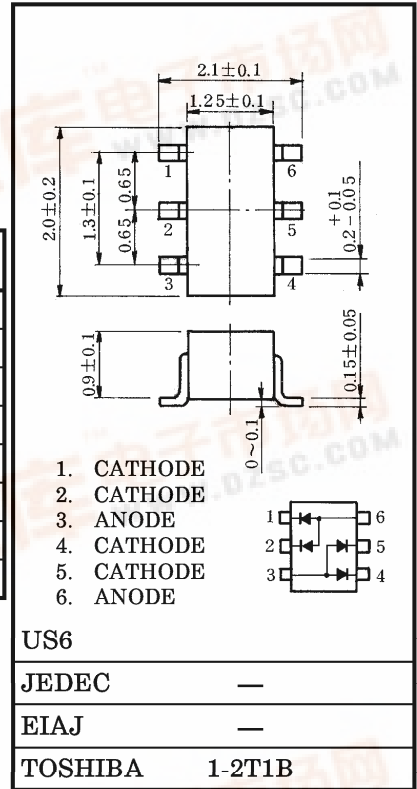
TOSHIBA DIODE SILICON EPITAXIAL PLANAR TYPE

HN1D01FU

ULTRA HIGH SPEED SWITCHING APPLICATION.

- Small Package
- Low Forward Voltage : $V_F(3) = 0.92V$ (Typ.)
- Fast Reverse Recovery Time : $t_{rr} = 1.6ns$ (Typ.)
- Small Total Capacitance : $C_T = 2.2pF$ (Typ.)

Unit in mm



MAXIMUM RATINGS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum (Peak) Reverse Voltage	V_{RM}	85	V
Reverse Voltage	V_R	80	V
Maximum (Peak) Forward Current	I_{FM}	300*	mA
Average Forward Current	I_O	100*	mA
Surge Current (10ms)	I_{FSM}	2*	A
Power Dissipation	P	200	mW
Junction Temperature	T_j	125	$^\circ C$
Storage Temperature	T_{stg}	-55~125	$^\circ C$

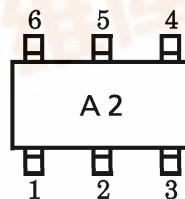
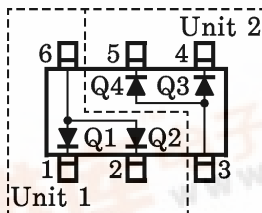
* : This is the Maximum Ratings of single diode (Q1 or Q2 or Q3 or Q4).
In the case of using Unit 1 and Unit 2 independently or simultaneously, the Maximum Ratings per diode is 75% of the single diode one.

ELECTRICAL CHARACTERISTICS (Q1, Q2, Q3, Q4 COMMON, $T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage	$V_F(1)$	$I_F = 1mA$	—	0.61	—	V
	$V_F(2)$	$I_F = 10mA$	—	0.74	—	
	$V_F(3)$	$I_F = 100mA$	—	0.92	1.20	
Reverse Current	$I_R(1)$	$V_R = 30V$	—	—	0.1	μA
	$I_R(2)$	$V_R = 80V$	—	—	0.5	
Total Capacitance	C_T	$V_R = 0, f = 1MHz$	—	2.2	4.0	pF
Reverse Recovery Time	t_{rr}	$I_F = 10mA$ (Fig. 1)	—	1.6	4.0	ns

PIN ASSIGNMENT (TOP VIEW)

Marking

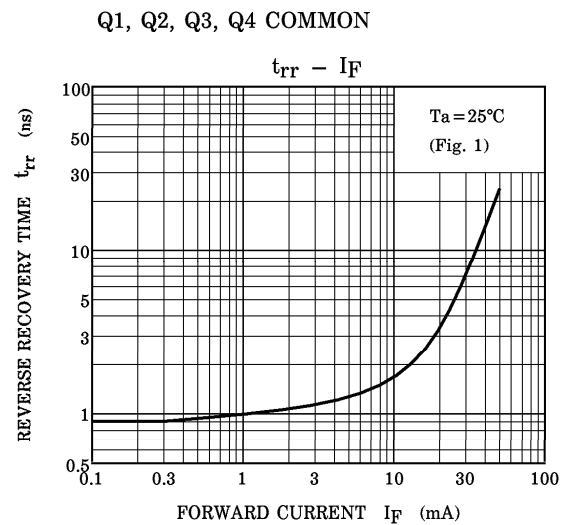
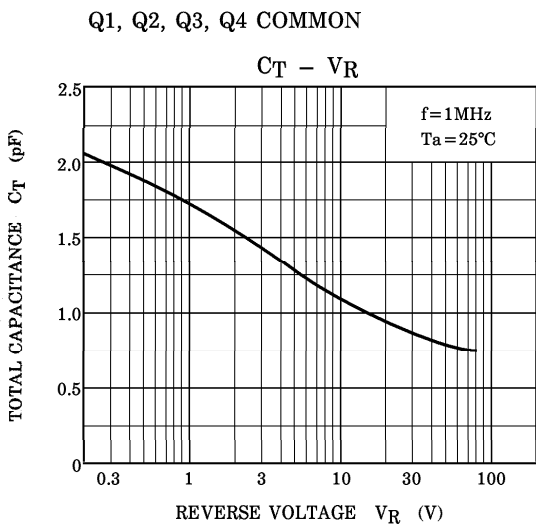
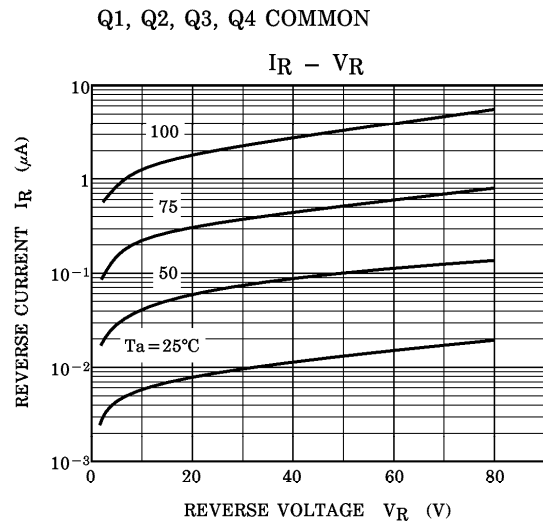
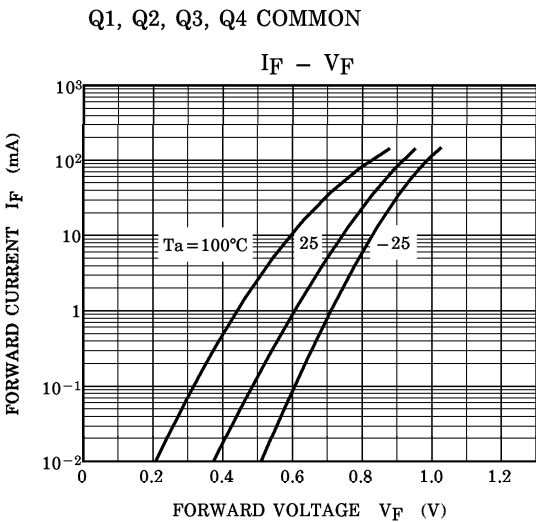
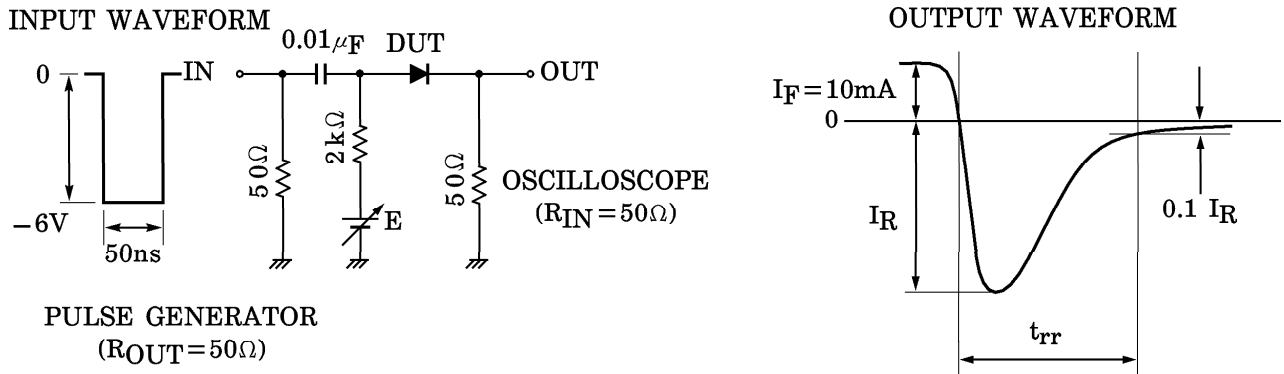


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Fig. 1 REVERSE RECOVERY TIME (t_{rr}) TEST CIRCUIT



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